

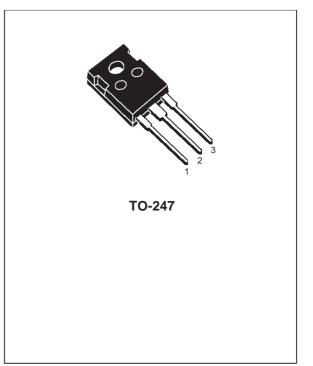
VB923 HIGH VOLTAGE IGNITION COIL DRIVER POWER IC

- NO EXTERNAL COMPONENT REQUIRED
- INTEGRATED HIGH VOLTAGE CLAMP
- COIL CURRENT LIMIT INTERNALLY SET
- HIGH RUGGEDNESS

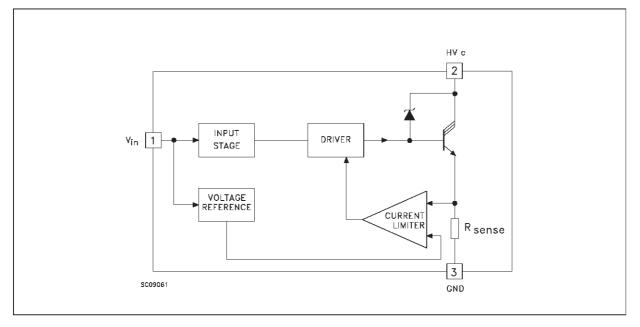
DESCRIPTION

The VB923 is a monolithic high voltage integrated circuits made using STMicroelectronics VIPower Technology, which combines a vertical current flow power trilinton with a coil current limiting circuit and a collector voltage clamping.

The device is peculiarly suitable for application in high performance electronic car ignition, where coil current limitation and voltage clamping are required.



BLOCK DIAGRAM



ABSOLUTE MAXIMUM RATING

Symbol	Parameter	Value	Unit
HVc	Collector Voltage	Internally Limited	V
Ι _c	Collector Current	Internally Limited	A
l _{in}	Input Current	40	mA
Ptot	Total Dissipation at $T_c = 25 \ ^{\circ}C$	150	W
T _{stg}	Storage Temperature	-40 to 150	°C
Tj	Operating Junction Temperature	-40 to150	°C
E _{s/b}	Avalanche Energy	350	mJ

THERMAL DATA

Symbol	Parameter	Value	Unit
R _{thj-case}	Thermal Resistance Junction-case Max	0.83	°C/W
$R_{thj-amb}$	Thermal Resistance Junction-ambient Max	30	°C/W

ELECTRICAL CHARACTERISTICS ($V_{batt} = 14 V$, HEI Coil = xx, $T_{case} = 25 °C$

unless otherwise specified)

Symbol	Parameter	Test Conditions	Min.	Тур.	Max.	Unit
I _{cgo}	Collector Cut-off Current	$V_{in} = 0$ $HV_c = 200 V$			250	μA
VcI	Clamping Voltage	$-40 < T_j < 125 \ ^{\circ}C \qquad I_c = 5 \ A$	350	400	500	V
V _{cg(sat)}	Power Stage Saturation Voltage	$I_c = 5 A$ $V_{in} = 4 V$		2	2.5	V
I _{cl} *	Coil Current Limit	$-30 \le T_j \le 50$ °C	6.0	6.6	7.2	A
V _f **	Diode Forward Voltage	I _f = 10 A			3.5	V
V_{inCL}	Input Voltage During On State	$\begin{array}{ll} -30 \leq T_j \leq 120 \ ^oC I_c = 5 \ A \\ I_{in} = 10 \ mA see \ note \ 1 \end{array}$			4	V
V_{inTH}	Threshold Input Voltage	$\begin{array}{ll} -30 \leq T_{j} \leq 120 \ ^{o}\text{C} \qquad I_{c} = 5 \ \text{A} \\ \text{see note } 2 \end{array}$	0.5		4	V
t _{d(off)}	Switching Time	$I_c = 3 A$ $L = 6 mH$ (see fig.1)	15		40	μs

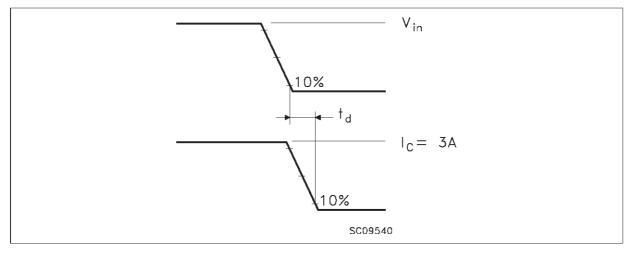
* I_{CL} is measured 1ms after the maximum peak ** Pulsed: Pulse duration = $300 \,\mu s$, duty cycle 1.5 %

Note 2: The device is biased with 14V on collector with respect o emitter. Then a voltage ramp (0 to 5V) is put on input. VinTH is the input voltage when the device is in on-state with $I_C=5A$

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Note 1: After adjusting input signal (frequency and duty) to be I_C = 5A, V_{in} (Tr ON) should be measured.

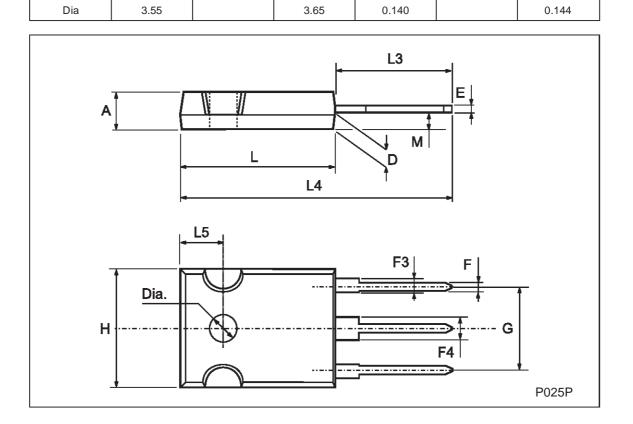
Fig. 1 Switching Time





DIM.	mm			inch		
	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.
А	4.7		5.3	0.185		0.209
D	2.2		2.6	0.087		0.102
E	0.4		0.8	0.016		0.031
F	1		1.4	0.039		0.055
F3	2		2.4	0.079		0.094
F4	3		3.4	0.118		0.134
G		10.9			0.429	
Н	15.3		15.9	0.602		0.626
L	19.7		20.3	0.776		0.779
L3	14.2		14.8	0.559	0.413	0.582
L4		34.6			1.362	
L5		5.5			0.217	
М	2		3	0.079		0.118

TO-247 MECHANICAL DATA



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